TinyLogic UHS D-Type, Flip-Flop with Preset and Clear

Description

The NC7SZ74 is a single, D–type, CMOS flip–flop with preset and clear from ON Semiconductor ultra high–speed series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive, while maintaining low static power dissipation over a very broad V_{CC} operating range of 1.65 V to 5.5 V V_{CC} . The inputs and outputs are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V, independent of V_{CC} operating voltage.

The signal level applied to the D input is transferred to the Q output during the positive—going transition of the CLK pulse.

Features

- Ultra-High Speed: t_{PD} 2.6 ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Power Down High-Impedance Inputs/Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise/EMI Reduction Circuitry

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US8 CASE 846AN UQFN8 1.6x1.6, 0.5P CASE 523AY

CONNECTION DIAGRAMS

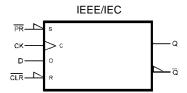
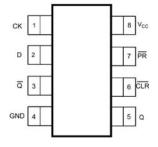


Figure 1. Logic Symbol

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Pin Configurations



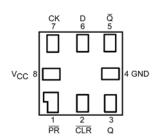


Figure 2. USB (Top View)

Figure 3. MicorPak™ (Top Through View)

PIN DEFINITIONS

Pin # US8	Pin # MicroPak	Name	Description
1	7	CK	Clock Pulse Input
2	6	D	Data Input
3	5	Q	Flip-Flop Output
4	4	GND	Ground
5	3	Q	Flip-Flop Output
6	2	CLR	Direct Clear Input
7	1	PR	Direct Preset Input
8	8	Vcc	Supply Voltage

ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method [†]
NC7SZ74K8X	SZ74	8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide	3000 Units on Tape & Reel
NC7SZ74L8X	N9	8-Lead MicroPak, 1.6 mm Wide	5000 Units on Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

FUNCTION TABLE

	Inp	uts		Out		
/CLR	/PR	D	СК	Q	/Q	Function
L	Н	Х	X	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	
Н	Н	L	↑	L	Н	
Н	Н	Н	↑	Н	L	
Н	Н	X	\	Q _n	/Q _n	No Change

H = HIGH Logic Level

Qn = No change in data

X = Immaterial

↓= Falling Edge

L = LOW Logic Level

Z = High Impedance

↑ = Rising Edge

ABSOLUTE MAXIMUM RATINGS

Symbol	Р	Min.	Max.	Unit	
Vcc	Supply Voltage		-0.5	6.5	V
Vin	DC Input Voltage		-0.5	6.5	V
Vouт	DC Output Voltage		-0.5	6.5	V
lıĸ	DC Input Diode Current	V _{IN} < 0V		-50	mA
Іок	DC Output Diode Current	V _{OUT} < 0V		-50	mA
Іоит	DC Output Source/Sink Current			±50	mA
Icc or Ignd	DC V _{CC} or Ground Current			±50	mA
Tstg	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias			+150	°C
TL	Junction Lead Temperature (Solde	ering, 10 Seconds)		+260	°C
P _D	Power Dissipation at +85@C			250	mW
ESD	Human Body Model, JEDEC:JESE	D22-A114		5000	V
	Charge Device Model: JEDEC:JES	SD22-C101		2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min.	Max.	Unit
Vcc	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.50	5.50	
VIN	Input Voltage		0	5.5	V
Vout	Output Voltage	Active State	0	Vcc	V
		3-State	0	5.5	

RECOMMENDED OPERATING CONDITIONS (continued)

Symbol	Parameter	Conditions	Min.	Max.	Unit
t _r , t _f	Input Rise and Fall Times	V_{CC} = 1.8 V, 2.5 V ± 0.2 V	0	20	ns/V
		V _{CC} = 3.3 V ± 0.3 V	0	10	
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0	5	
T_A	Operating Temperature		-40	+85	°C
0	Thermal Resistance	US8		250	°C/W
θ_{JA}		MicroPak™ –8		280	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

NOTE: Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTRICAL CHARACTERISTICS

	Parameter			T,	₄ = +25°	°C	$T_A = -40$	to +85°C	
Symbol		Vcc	Conditions	Min.	Тур.	Max.	Min.	Max.	Units
VIH	HIGH Level Control	1.65 to 1.95		0.65 V _{CC}			0.65 V _{CC}		V
	Input Voltage	2.30 to 5.50		0.70 V _{CC}			0.70 V _{CC}		
VIL	LOW Level Control	1.65 to 1.95				0.35 V _{CC}		0.35 V _{CC}	V
	Input Voltage	2.30 to 5.50				0.30 V _{CC}		0.30 V _{CC}	
Vон		1.65	$V_{IN} = V_{IH}, I_{OH} = -100 \mu A$	1.55	1.65		1.55		V
	Voltage	2.30		2.20	2.30		2.20		
		3.00		2.90	3.00		2.90		
		4.50		4.40	4.50		4.40		
		1.65	$I_{OH} = -4 \text{ mA}$	1.29	1.52		1.29		
		2.30	$I_{OH} = -8 \text{ mA}$	1.90	2.15		1.90		
		3.00	I _{OH} = -16 mA	2.40	2.80		2.40		
		3.00	I _{OH} = -24 mA	2.30	2.68		2.30		
		4.50	$I_{OH} = -32 \text{ mA}$	3.80	4.20		3.80		
	LOW Level Control Output Voltage	1.65	$V_{IN} = V_{IH}, I_{OL} = 100 \mu A$			0.10		0.10	V
	Output voltage	2.30				0.10		0.10	
		3.00				0.10		0.10	
		4.50				0.10		0.10	
		1.65	I _{OL} = 4 mA		0.10	0.24		0.24	
		2.30	I _{OL} = 8 mA		0.10	0.30		0.30	
		3.00	I _{OL} = 16 mA		0.15	0.40		0.40	
		3.00	I _{OL} = 24 mA		0.22	0.55		0.55	
		4.50	I _{OL} = 32 mA		0.22	0.55		0.55	
lin	Input Leakage Current	1.65 to 5.5	$0 \le V_{IN} \le 5.5 \text{ V}$			±0.1		±1.0	μΑ
loff	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V			1		10	μΑ
Icc	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V, GND			1		10	μΑ

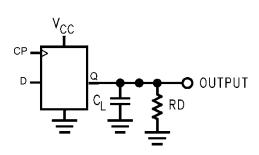
AC ELECTRICAL CHARACTERISTICS

				T	A = +25°	С	$T_A = -40$	to +85°C]	
Symbol	Parameter	V _{CC}	Conditions	Min.	Тур.	Max.	Min.	Max.	Units	Figure
fмах	Maximum Clock	1.80 ± 0.15	C _L = 15 pF	75			75		ns	Figure 4
	Frequency	2.50 ± 0.20	$R_D = 1 M\Omega$ $S_1 = Open$	150			150			Figure 8
		3.30 ± 0.30	· ·	200			200			
		5.00 ± 0.50		250			250			
		3.30 ± 0.50	C _L = 50 pF	175			175			
		5.00 ± 0.50	$R_D = 500 \Omega$, $S_1 = Open$	200			200			
tplh, tphl	Propagation Delay CK to Q, /Q	1.80 ± 0.15	C _L = 15pF,		6.5	12.5		13.0	ns	Figure 4
	10 Q, /Q	2.50 ± 0.20	$R_D = 1 M\Omega$ $S_1 = Open$		3.8	7.5		8.0		Figure 6
		3.30 ± 0.30			2.8	6.5		7.0		
		5.00 ± 0.50			2.2	4.5		5.0		
		3.30 ± 0.30	C _L = 50 pF		3.4	7.0		7.5		
		5.00 ± 0.50	$R_D = 500 \Omega$, $S_1 = Open$		2.6	5.0		5.5		
tplh, tphl	Propagation Delay	1.80 ± 0.15	C _L = 15 pF,		6.5	14.0		14.5	ns	Figure 4
	/CLR, /PR to Q, /Q	2.50 ± 0.20	$R_L = 1 M\Omega$ $S_1 = Open$		3.8	9.0		9.5		Figure 6
		3.30 ± 0.30	1		2.8	6.5		7.0		
		5.00 ± 0.50			2.2	5.0		5.5		
		3.30 ± 0.30	C _L = 50 pF,		3.4	7.0		7.5		
		5.00 ± 0.50	$R_D = 500 \Omega$		2.6	5.0		5.5		
t _S	Setup Time CK to D	1.80 ± 0.15	C _L = 15 pF,	6.5			6.5		ns	Figure 4
		2.50 ± 0.20	$R_L = 1 M\Omega$ $S_1 = Open$	3.5			3.5			Figure 7
		3.30 ± 0.30		2.0			2.0			
		5.00 ± 0.50		1.5			1.5			
		3.30 ± 0.30	C _L = 50 pF,	2.0			2.0			
		5.00 ± 0.50	$R_D = 500 \Omega$, $S_1 = Open$	1.5			1.5			
t _H	Hold Time, CK to D	1.80 ± 0.15	C _L = 15 pF,	0.5			0.5		ns	Figure 4
		2.50 ± 0.20	$R_L = 1 M\Omega$ $S_1 = Open$	0.5			0.5			Figure 7
		3.30 ± 0.30		0.5			0.5			
		5.00 ± 0.50		0.5			0.5			
		3.30 ± 0.30	C _L = 50 pF,	0.5			0.5			
		5.00 ± 0.50	$R_D = 500 \Omega$, $S_1 = Open$	0.5			0.5			
t _W	Pulse Width, CK,	1.80 ± 0.15	C _L = 15 pF,	6.0			6.0		ns	Figure 4
	/PR, /CLR	2.50 ± 0.20	$R_L = 1 M\Omega$ $S_1 = Open$	4.0			4.0			Figure 8
		3.30 ± 0.30	1	3.0			3.0			
		5.00 ± 0.50	1	2.0			2.0			
		3.30 ± 0.30	C _L =50pF,	3.0			3.0			
	I	5.00 ± 0.50	$R_D = 500\Omega$,		1	1		İ	1	1

AC ELECTRICAL CHARACTERISTICS (continued)

				T	A = +25°	С	$T_A = -40$	to +85°C		
Symbol	Parameter	V _{CC}	Conditions	Min.	Тур.	Max.	Min.	Max.	Units	Figure
trec	Recover Time /CLR,	1.80 ± 0.15	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	8.0			8.0		ns	Figure 7
	/PR to CK	2.50 ± 0.20	$S_1 = Open$	4.5			4.5			
		3.30 ± 0.30		3.0			3.0			
		5.00 ± 0.50		3.0			3.0			
		3.30 ± 0.30	$C_L = 50 \text{ pF},$	3.0			3.0			
		5.00 ± 0.50	$R_D = 500 \Omega$, $S_1 = Open$	3.0			3.0			
Cin	Input Capacitance	0			3				pF	
Соит	Output Capacitance	0			4				pF	
СРД	Power Dissipation	3.30			10				pF	
	Capacitance (Note 1)	5.00			12					

^{1.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD})(V_{CC})(f_{IN}) + (I_{CC}static).$



2. C_L includes load and stray capacitance. Input PRR = $1.0 \text{ MHz t}_{\text{W}} = 500 \text{ ns}.$

Figure 4. AC Test Circuit

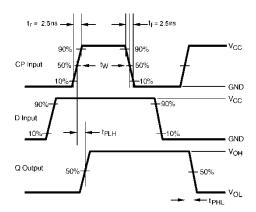
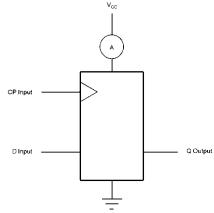


Figure 6. AC Waveforms



- $\begin{array}{ll} \text{3.} & \text{CP input} = \text{AC Waveforms} \ t_r = t_f = 2.5 \ \text{ns.} \\ \text{4.} & \text{CP input PRR} = 10 \ \text{MHz; Duty Cycle} = 50\%. \\ \text{5.} & \text{D input PRR} = 5 \ \text{MHz; Duty Cycle} = 50\%. \\ \end{array}$

Figure 5. AC Test Circuit

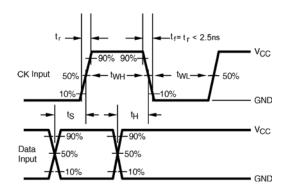


Figure 7. AC Waveforms

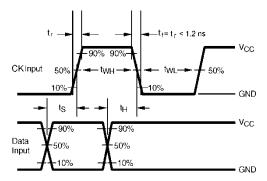
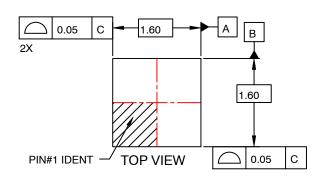
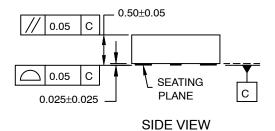


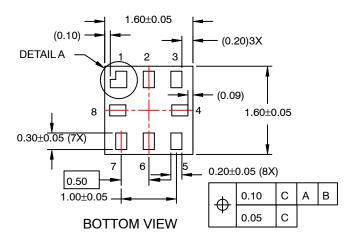
Figure 8. AC Waveforms

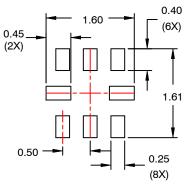
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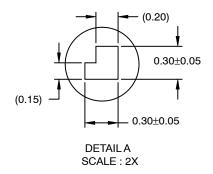




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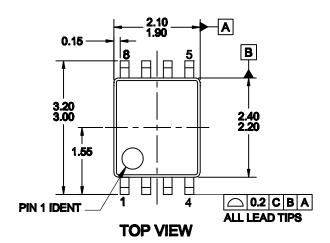


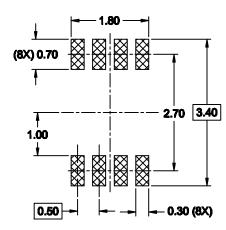
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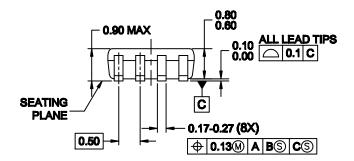
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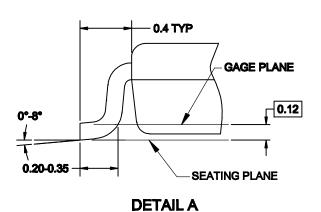
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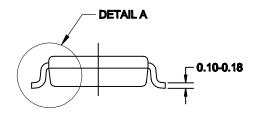


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